



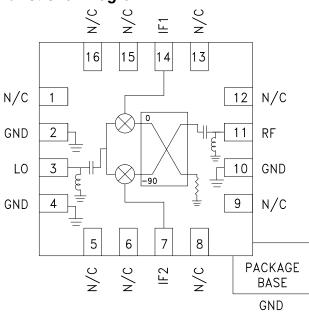
# GaAs MMIC I/Q MIXER 24 - 28 GHz

## Typical Applications

The HMC1063LP3E is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- · Military Radar, EW & ELINT
- Satellite Communications
- Sensors

## **Functional Diagram**



#### **Features**

Low LO Power: 10 dBm

Wide IF Bandwidth: DC - 3 GHz

Image Rejection: 21 dBc LO / RF Isolation: 40 dB High Input IP3: 17 dBm

16 Lead 3x3 mm SMT Package: 9 mm<sup>2</sup>

## **General Description**

The HMC1063LP3E is a compact I/Q MMIC mixer in a leadless "Pb free" SMT package, which can be used as either an Image Reject Mixer or a Single Sideband Upconverter. The mixer utilizes two standard Hittite double balanced mixer cells and a 90 degree hybrid fabricated in a GaAs Schottky diode process. A low frequency quadrature hybrid was used to produce a 1000 MHz LSB IF output. This product is a much smaller alternative to hybrid style Image Reject Mixers and Single Sideband Upconverter assemblies. The HMC1063LP3E eliminates the need for wire bonding and allows the use of surface mount manufacturing techniques.

# Electrical Specifications $^{[1][2]}$ , $T_A = +25$ °C, IF = 1000 MHz, LSB, LO = +10 dBm

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, RF		24 - 27	,		27- 28		GHz
Frequency Range, LO	21 - 30		24 - 31		GHz		
Frequency Range, IF		DC - 3			DC - 3		GHz
Conversion Gain	-11.5	-9.5		-11.5	-9.5		dB
Image Rejection	15	21		13	21		dBc
LO to RF Isolation	30	42		28	36		dB
LO to IF Isolation		40			40		dB
IP3 (Input)		18			16		dBm
Amplitude Balance [2]		1			1		dB
Phase Balance <sup>[2]</sup>		-2			+2		Deg

<sup>[1]</sup> Unless otherwise noted all measurements performed as downconverter.

<sup>[2]</sup> Data taken without external 90° hybrid.

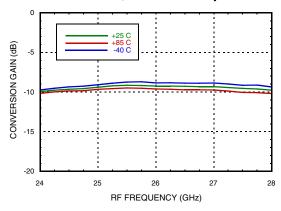




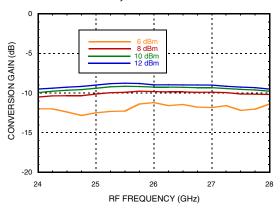
# GaAs MMIC I/Q MIXER 24 - 28 GHz

# Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

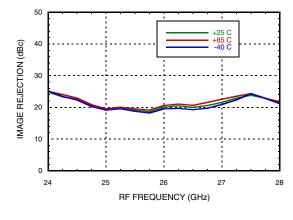
### Conversion Gain, LSB vs. Temperature



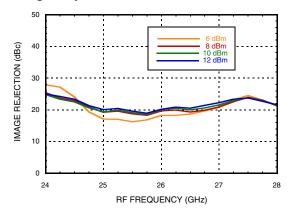
#### Conversion Gain, LSB vs. LO Drive



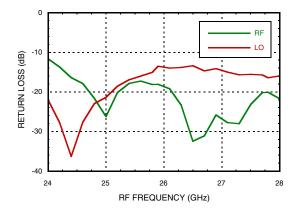
## Image Rejection, LSB vs. Temperature



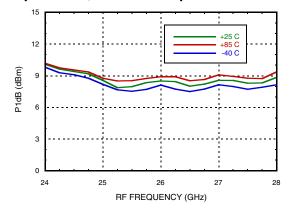
### Image Rejection, LSB vs. LO Drive



#### **Return Loss**



### Input P1dB, LSB vs. Temperature



#### [1] Data taken without external IF 90° hybrid

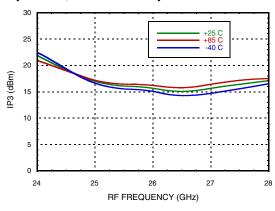




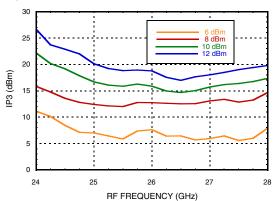
# GaAs MMIC I/Q MIXER 24 - 28 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

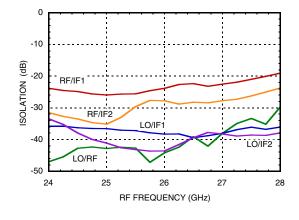
#### Input IP3, LSB vs. Temperature



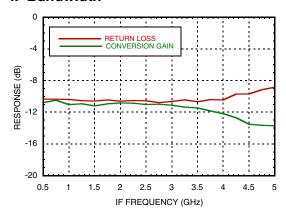
## Input IP3, LSB vs. LO Drive



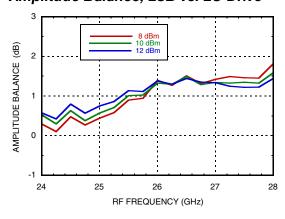
#### Isolations



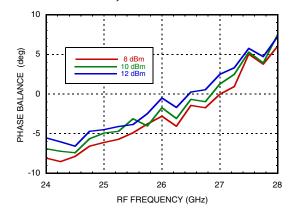
#### IF Bandwidth\*



#### Amplitude Balance, LSB vs. LO Drive



#### Phase Balance, LSB vs. LO Drive



<sup>\*</sup> Conversion gain data taken with external IF hybrid.

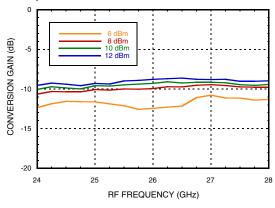




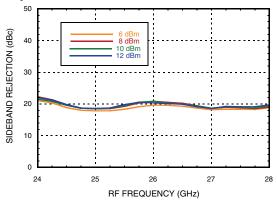
# GaAs MMIC I/Q MIXER 24 - 28 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

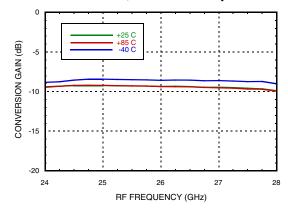
# Upconverter Performance, Conversion Gain, LSB vs. LO Drive



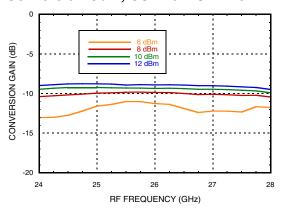
# Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



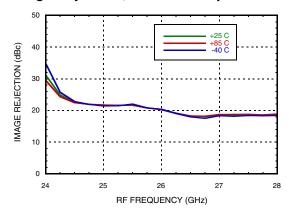
## Conversion Gain, USB vs. Temperature



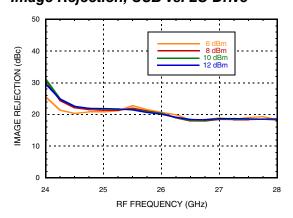
### Conversion Gain, USB vs. LO Drive



### Image Rejection, USB vs. Temperature



## Image Rejection, USB vs. LO Drive



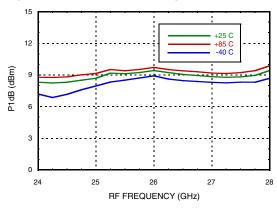




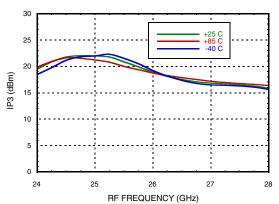
## GaAs MMIC I/Q MIXER 24 - 28 GHz

# Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

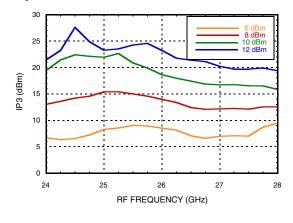
## Input P1dB, USB vs. Temperature



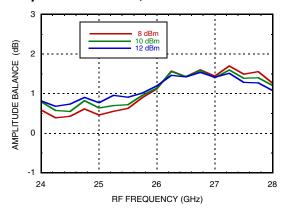
## Input IP3, USB vs. Temperature



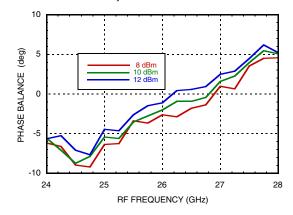
### Input IP3, USB vs. LO Drive



### Amplitude Balance, USB vs. LO Drive



### Phase Balance, USB vs. LO Drive



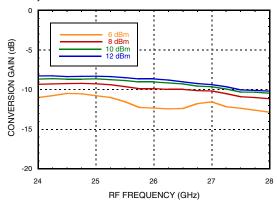




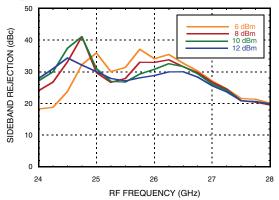
# GaAs MMIC I/Q MIXER 24 - 28 GHz

# Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 1000 MHz

# Upconverter Performance, Conversion Gain, USB vs. LO Drive



# Upconverter Performance, Sideband Rejection, USB vs. LO Drive,



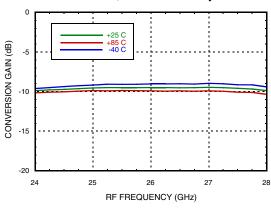




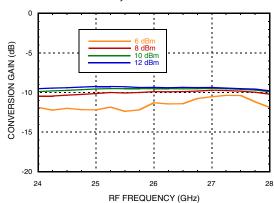
## GaAs MMIC I/Q MIXER 24 - 28 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

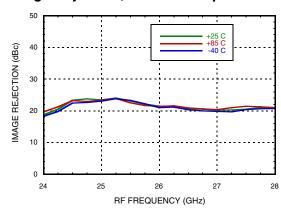
### Conversion Gain, LSB vs. Temperature



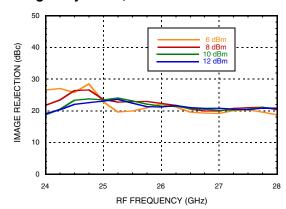
#### Conversion Gain, LSB vs. LO Drive



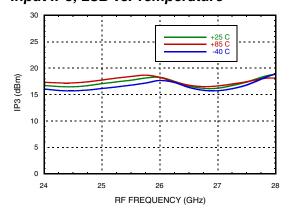
### Image Rejection, LSB vs. Temperature



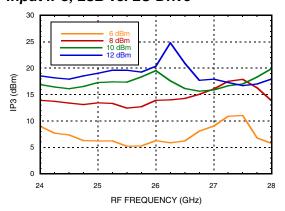
### Image Rejection, LSB vs. LO Drive



#### Input IP3, LSB vs. Temperature



Input IP3, LSB vs. LO Drive

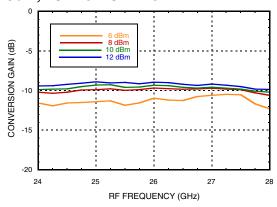




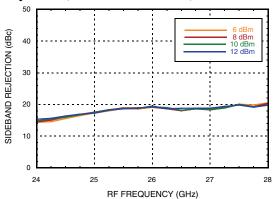
# GaAs MMIC I/Q MIXER 24 - 28 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

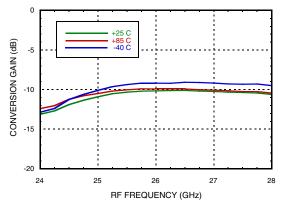
# Upconverter Performance, Conversion Gain, LSB vs. LO Drive



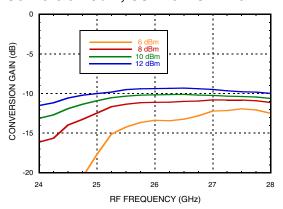
# Upconverter Performance, Sideband Rejection, LSB vs. LO Drive,



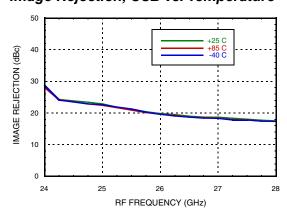
## Conversion Gain, USB vs. Temperature



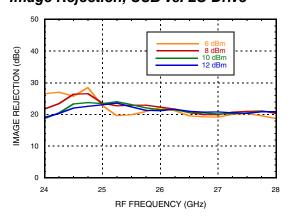
### Conversion Gain, USB vs. LO Drive



### Image Rejection, USB vs. Temperature



## Image Rejection, USB vs. LO Drive



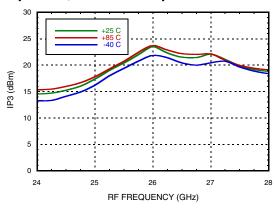




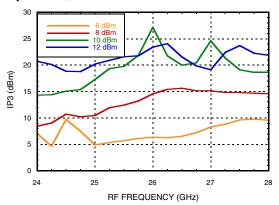
# GaAs MMIC I/Q MIXER 24 - 28 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

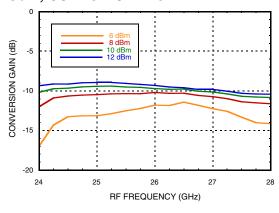
## Input IP3, USB vs. Temperature



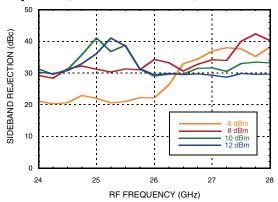
## Input IP3, USB vs. LO Drive



# Upconverter Performance, Conversion Gain, USB vs. LO Drive



# Upconverter Performance, Sideband Rejection, USB vs. LO Drive,







# GaAs MMIC I/Q MIXER 24 - 28 GHz

## Harmonics of LO

105 (011)	nLO Spur at RF Port			
LO Freq. (GHz)	1	2	3	
23	36.6	43.3	х	
24	33.8	46.4	х	
25	32.1	49.4	х	
26	29.6	х	х	
27	31.8	х	х	
28	32.8	х	х	

LO = + 10 dBm Values in dBc below LO level measured at RF Port.

## **MxN Spurious Outputs**

	nLO				
mRF	0	1	2	3	4
0	XX	1	28	x	х
1	8	0	34	60	х
2	95	53	51	58	87
3	х	97	97	97	97
4	х	х	х	97	97

RF = 22 GHz @ -10 dBm

LO = 23 GHz @ +10 dBm

Data taken without IF hybrid

All values in dBc below IF power level





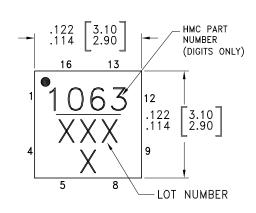
# GaAs MMIC I/Q MIXER 24 - 28 GHz

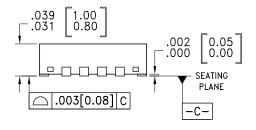
## **Absolute Maximum Ratings**

IF Input (At LO = 10 dBm and RF = -10 dBm)	+11.5 dBm	
RF Input (At 10 dBm LO Power)	+13 dBm	
LO Input (At -10 dBm RF Power)	+14.5 dBm	
Channel Temperature	175 °C	
Continuous Pdiss (T = 85°C) (derate 6 mW/°C above 85°C)	550 mW	
Thermal Resistance (channel to ground paddle)	164 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
ESD Sensitivity (HBM)	Class 1A	



## **Outline Drawing**





# 

#### NOTES:

- PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILCON IMPREGNATED.
- 2. LEAD AND GROUND PADDLE MATERIAL: COPPER ALLOY.
- 3. LEAD AND GROUND PADDLE PLATING: 100% MATTE TIN.
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 6. PAD BURR LENGTH SHALL BE 0.15mm MAX. PAD BURR HEIGHT SHALL BE 0.05mm MAX.
- 7. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

#### **Package Information**

Part Number	Package Body Material	Lead Finish	MSL Rating [2]	Package Marking [1]
HMC1063LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1	<u>H1063</u> XXXX

<sup>[1] 4-</sup>Digit lot number XXXX

[2] Max peak reflow temperature of 260  $^{\circ}\text{C}$ 





# GaAs MMIC I/Q MIXER 24 - 28 GHz

## **Pin Descriptions**

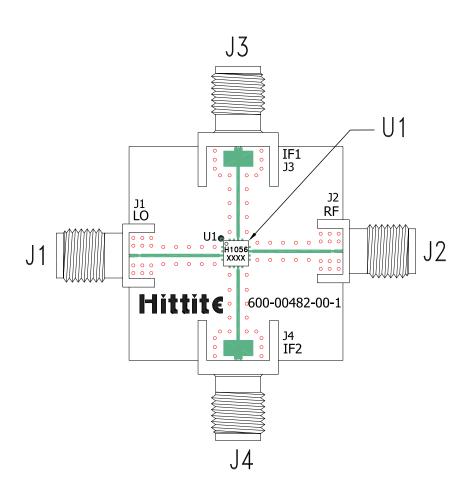
Pin Number	Function	Description	Interface Schematic
1, 5, 6, 8, 9, 12, 13, 15, 16	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2, 4, 10	GND	These pins and exposed ground paddle must be connected to RF/DC ground	O GND
3	LO	This pin is DC coupled and matched to 50 Ohns	10 O
7	IF2	Differential IF input pins. For applications not requiring operation to DC, an off chip DC blocking capacitor should be used. For operation to DC this pin must not source/sink	IF1,IF2
14	IF1	more than 3 mA of currrent or part non function and and possible part failure will result.	
11	RFOUT	This pin is DC coupled and matched to 50 Ohms.	RF O





## GaAs MMIC I/Q MIXER 24 - 28 GHz

#### **Evaluation PCB**



#### List of Materials for Evaluation PCB EVAL01-HMC1063LP3 [1]

Item	Description	
J1, J2	PCB mount K Connector SRI	
J3, J4	PCB mount SMA Connector Johnson	
U1	HMC1063LP3E Downconverter	
PCB [2]	600-00482-00-1 Evaluation Board	

[1] Reference this number when ordering complete evaluation PCB  $\,$ 

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.





MIXERS - I/Q MIXERS, IRMS & RECEIVERS - SMT





Notes:

GaAs MMIC I/Q MIXER 24 - 28 GHz

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 HMC220BMS8GE
 HMC8192-SX
 LTC5569IUF#PBF
 HMC220BMS8GETR
 MAX2055EUP+TD
 M85C
 M74C
 CSM4TH
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 HMC141LH5
 HMC333TR
 HMC214MS8TR

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 F0502NLGI
 F1763NBGI
 MDS-189-PIN
 MAX2042AETP+
 MAX2032ETP+

 MAX2043ETX+
 CSM2-13
 CSM4T
 HMC1056LP4BETR
 LTC5510IUF#PBF
 LTC5553IUDB#TRMPBF